Supplementary Information

The 4*d* and 5*d* Bimetal Doped Tubular Silicon Clusters M₂Si₁₂ with M =

Nb, Ta, Mo and W: A Bimetallic Configuration Model

Hung Tan Pham,^{a,b} Devashis Majumdar,^c Jerzy Leszczynski^c and Minh Tho Nguyen^{d,1}

^a Computational Chemistry Research Group, Ton Duc Thang University, Ho Chi Minh City, Vietnam

^b Faculty of Applied Sciences, Ton Duc Thang University, Ho Chi Minh City, Vietnam

^c Interdisciplinary Center for Nanotoxicity, Department of Chemistry and Biochemistry, Jackson State University, Jackson, Mississippi 39217, USA

^d Department of Chemistry, KU Leuven, Celestijnenlaan 200F, B-3001 Leuven, Belgium

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Table S1. the relative energy (kcal/mol) of lower-lying spin state of dimers. M: multiplicity.

Figure S1. The shape of lower-lying isomer of Nb₂Si₁₂, Nb₂Si₁₂²⁻, Ta₂Si₁₂ and Ta₂Si₁₂²⁻ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

Figure S2. The shape of lower-lying isomer of Mo_2Si_{12} , $Mo_2Si_{12}^{2+}$, W_2Si_{12} and $W_2Si_{12}^{2+}$ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

¹Emails:<u>phamtanhung@tdt.edu.vn;dmajumdar@icnanotox.org;jerzy@icnanotox.org;minh.nguyen@chem.k</u><u>uleuven.be</u>

Figure S3. The shape of lower-lying isomer of Mo_2Si_{12} , $Mo_2Si_{12}^{2+}$, W_2Si_{12} and $W_2Si_{12}^{2+}$ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

Figure S4. The DOS and pDOS of Si₁₂Nb₂ cluster.

Figure S5. The DOS and pDOS of Si₁₂NbMo cluster.

Figure S6. The DOS and pDOS of $Si_{12}Ta_2$ cluster.

Figure S7. The DOS and pDOS of $Si_{12}W_2$ cluster.

Figure S8. The DOS and pDOS of Si₁₂TaW cluster.

Table S1.

Specie	M=1	M=3	M=5	M=7	Specie	M=2	M=4	M=6	M=8
Mo ₂	0.0	25.0	40.0	55.6	MoNb	0.0	21.9	42.7	73.3
Nb ₂	8.4	0.0	22.0	49.2	WTa	2.2	0.0	22.8	49.4
W ₂	0.0	7.8	19.6	36.4					
Ta ₂	30.7	2.0	0.0	27.1					



Nb2.A $C_{2v} {}^{1}A_{1} 0.00$ $C_{6v} {}^{3}A_{1} 9.37$



Nb2.B C_s ¹A' 20.89 C₁ ³A 23.12



Nb2.C C₁ ¹A 19.72 C₁ ³A 31.78 Nb2Si₁₂



Nb2.D C₁ ¹A 20.80 C₁ ³A 28.39



Nb2.E C1 ¹A 15.42 C1 ³A 23.12



Nb2.da.A $C_{6\nu}{}^{1}A_{1} 0.00$



Nb2.da.B *C*_{6v} ¹A₁ 26.9

Ta2.B

 C_1 ¹A 14.59

 C_1^{3} A 21.92



Nb2.da.C C_s ¹A' 28.04 **Si**₁₂Nb2²⁻



Nb2.da.D C₁ ¹A 28.51



Nb2.da.E *C*¹ A 32.95



 $\begin{array}{c} {\rm Ta2.A} \\ C_{2\rm v} \ {}^1\!{\rm A}_1 \ 0.00 \\ C_6 \ {}^3\!{\rm A} \ 10.69 \end{array}$



Ta2.C C_s ¹A' 18.40 C_1 ³A 21.92 **Ta2Si**₁₂



Ta2.D C₁ ¹A 18.51 C₁ ³A 19.55



Ta2.E C₁ ¹A 20.75 C₁ ³A 33.12



Ta2.da.A $C_{6v}{}^{1}A_{1} 0.00$



Ta2.da.B C_s ¹A'10.39





Ta2.da.D *C*₁ ¹A 23.86



Ta2.da.E C_1 ¹A 25.59





 $\frac{Mo2.A}{C_{6\nu}\,{}^{1}A_{1}\,0.00}\\C_{2\nu}\,{}^{3}A_{1}\,28.07$



Mo2.B C₁ ¹A 26.60 C₁ ³A 30.44



Mo2.C C₁ ¹A 36.23 C₁ ³A 42.19 Mo₂Si₁₂



Mo2.D C_s ¹A' 30.20 C_s ³A' 44.60



Mo2.E C₁ ¹A 36.89 C₁ ³A 42.70



Si12Mo2-dica_2 C_{2v} ¹A₁ 0.00



Si12Mo2-dica_1 $C_{6\nu}$ ¹A₁ 6.85



Si12Mo2-dica_3 C_1 ¹A 22.42 **Mo₂Si₁₂²⁺**



Si12Mo2-dica_4

 C_1 ¹A 24.92



Si12Mo2-dica_5 C1 ¹A 25.50



 $\begin{array}{c} \text{W2.n.A} \\ C_{6\nu} \, {}^{1}\text{A}_{1} \, 0.00 \\ C_{2\nu} \, {}^{3}\text{A}_{1} \, 32.78 \end{array}$



W2.B C₁ ¹A 24.26 C₁ ³A 32.19



W2.C $C_s {}^{1}A' 28.24$ $C_s {}^{3}A' 43.82$ **W**₂Si₁₂



C_s ¹A' 33.28 *C_s* ³A' 50.42



W2.E C₁ ¹A 34.68 C₁ ³A 41.19



Si12W2-dica_2 $C_{2v} {}^{1}A_{1} 0.00$



Si12W2-dica_1 C_{6v} ¹A₁ 16.68



Si12W2-dica_3 C_1 ¹A 23.86 $Si_{12}W_2^{2+}$

Figure S2



Si12W2-dica_8 $C_1 {}^{1}A 23.38$



Si12W2-dica_6 C_1 ¹A 25.38



NbMo.c.A $C_{2v} {}^{1}A_{1} 0.00$



NbMo.c.B

 C_1 ¹A 25.00



NbMo.c.C *C*^s ¹A' 28.23

NbMoSi₁₂+



NbMo.a.A $C_{6v} {}^{1}A_{1} 0.00$



NbMo.a.B C_{6v} ¹A₁ 22.84



NbMo.a.C *C*^s ¹A' 25.46 NbMoSi₁₂-





NbMo.a.D C_1 ¹A 27.36



NbMo.a.E C_1 ¹A 34.24











Figure S3



Figure S4.







Figure S6.







